Hot Plate Preparation (optional but optimal)

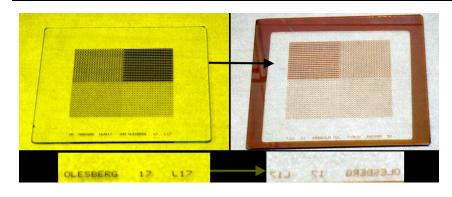
- 1. Clean both hot plates thoroughly with acetone using a paper towel.
- 2. Rinse hot plates with methanol. Rinse hot plates with isopropanol.
- 3. Dry hot plate surface with compressed N_2 gas.

Typical Procedure

- 1. Preheat first hot plate to 100°C. (See DataPlate® Hotplate manual.)
- 2. Blow any dust from FeO plate with compressed N₂.
- 3. Pre-bake plate for ten (10) minutes on first hot plate at 100°C.
- 4. Cool plate four (4) min on cold metal surface of second hot plate.
- 5. Blow any dust from FeO plate with compressed N_2 .
- 6. Heat first hot plate to 120°C.
- 7. Rinse patterned side of chrome mask with acetone; dry with compressed N₂.
- 8. Turn mask aligner, UV power supply and lamp ON. Note: See Karl Suss Mask Aligner manual.
- 9. Remove any shims from sample stage, and slide stage completely in to left.
- 10. Raise sample stage fully (stage lever turned to UP position).
- 11. Remove mask chuck and set aside.
- 12. Place chrome mask patterned-side down directly on top of photoresist-side of FeO mask.
- 13. Place sandwiched plates, FeO mask down, on center of sample stage.
- 14. Expose to UV for 30 sec.
- 15. Carefully remove *both* masks together from sample stage to avoid damage due to vacuum lock.
- 16. Immerse FeO plate in 15ml:60ml DI-H2O:AZ developer with agitation for 30 sec.
- 17. Rinse FeO plate immediately with DI H_2O , and dry thoroughly with compressed N_2 .
- 18. Inspect FeO plate with microscope.
 - Note: If necessary, further-develop in increments of 10 sec.
- 19. Bake FeO plate for ten (10) minutes on first hot plate at 120°C.
- 20. Prepare 280ml:140ml $H_20:HC1$ (or stock if available) in a large glass container.
- 21. Etch FeO plate approximately 2 min 40 sec in etchant with constant agitation.
- 22. Rinse plate with DI H_2O , and dry thoroughly with compressed N_2 .
- 23. Inspect etched regions for transparency.
- 24. Note: Continue etching in 15-25 sec intervals if etched areas are hazy when held up to light. Avoid over-etching.
- 25. Soak FeO plate in acetone for five (5) minutes and rinse thoroughly with DI H₂O.
- 26. Optional but optimal. Rinse with Kodak Photo-Flo and hot H₂0; thoroughly dry with compressed N₂.

Final Bake (for film hardness and chemical resistance)

- 1. Heat FeO plate at 120°C for 45 min on first hot plate.
- 2. Place FeO plate on cold plate for 4 min to cool.
- 3. Store plate in dust-free box.





The FeO copy (right) will have a "frame" due to size of UV window. The copied mask will be a mirror of original as noted by reversed label text in this example.

